



AMP2102DB SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Small and light rack mounted chassis
- Class AB linear LDMOS & GaN Hybrid design
- Dual-Band, manual switching ultra-broadband
- Suitable for all single channel modulation standards
- Built-in protection circuits
- Universal voltage AC power supply
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range Band A	100 - 1000 MHz	
Operating Frequency Range Band B	1.0 - 18.0 GHz	
Power Output @ Psat	5 Watt Min	CW
Power Gain	43 dB Min	
Power Gain Flatness	4.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	27dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	-25 dBc Typ	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	200 Watt Max	At rated Pout
Input Power Protection	+3 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1	<1 minute at rated Pout.

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 560 mm	2U rack mount
Weight	9 kg.	
RF Connectors In/Out	Type-N Female	
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

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OUTLINE DRAWING

